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# ***DISCRETE POWER DIODES and THYRISTORS***

## ***DATA BOOK***

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### INVERTER GRADE THYRISTORS

Puk Version

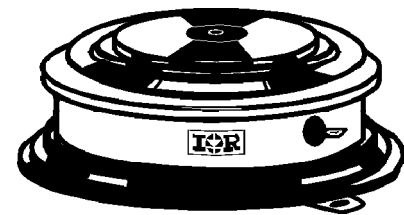
#### Features

- Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)
- All diffused design
- Center amplifying gate
- Guaranteed high  $dV/dt$
- Guaranteed high  $dI/dt$
- High surge current capability
- Low thermal impedance
- High speed performance

#### Typical Applications

- Inverters
- Choppers
- Induction heating
- All types of force-commutated converters

620A



case style TO-200AB (E-PUK)

### Major Ratings and Characteristics

Parameters	ST303C..C	Units	
$I_{T(AV)}$	620	A	
@ $T_{hs}$	55	°C	
$I_{T(RMS)}$	1180	A	
@ $T_{hs}$	25	°C	
$I_{TSM}$	@ 50Hz	7950	A
	@ 60Hz	8320	A
$I^2t$	@ 50Hz	316	KA <sup>2</sup> s
	@ 60Hz	289	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	400 to 1200	V	
$t_q$ range (*)	10 to 30	μs	
$T_J$	- 40 to 125	°C	

(\*)  $t_q = 10$  to  $20\mu s$  for 400 to 800V devices

# ST303C..C Series

## ELECTRICAL SPECIFICATIONS

### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , maximum repetitive peak voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_J$ max. mA
ST303C..C	04	400	500	50
	08	800	900	
	10	1000	1100	
	12	1200	1300	

### Current Carrying Capability

Frequency							Units
50Hz	1314	1130	2070	1940	6930	6270	A
400Hz	1260	1040	2190	1880	3440	2960	
1000Hz	900	700	1900	1590	1850	1540	
2500Hz	340	230	910	710	740	560	
Recovery voltage Vr	50	50	50	50	50	50	V
Voltage before turn-on Vd	$V_{DRM}$		$V_{DRM}$		$V_{DRM}$		V
Rise of on-state current di/dt	50	50	-	-	-	-	A/µs
Heatsink temperature	40	55	40	55	40	55	°C
Equivalent values for RC circuit	10Ω / 0.47µF		10Ω / 0.47µF		10Ω / 0.47µF		

### On-state Conduction

Parameter	ST303C..C	Units	Conditions		
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	620 (230)	A	180° conduction, half sine wave double side (single side) cooled		
	55 (85)	°C			
$I_{T(RMS)}$ Max. RMS on-state current	1180	A	DC @ 25°C heatsink temperature double side cooled		
$I_{TSM}$ Max. peak, one half cycle, non-repetitive surge current	7950		t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J$ max
	8320		t = 8.3ms	reapplied	
	6690		t = 10ms	100% $V_{RRM}$	
7000	t = 8.3ms	reapplied			
$I^2t$ Maximum $I^2t$ for fusing	316	KA²s	t = 10ms	No voltage	Initial $T_J = T_J$ max
	289		t = 8.3ms	reapplied	
	224		t = 10ms	100% $V_{RRM}$	
	204		t = 8.3ms	reapplied	
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	3160	KA²√s	t = 0.1 to 10ms, no voltage reapplied		

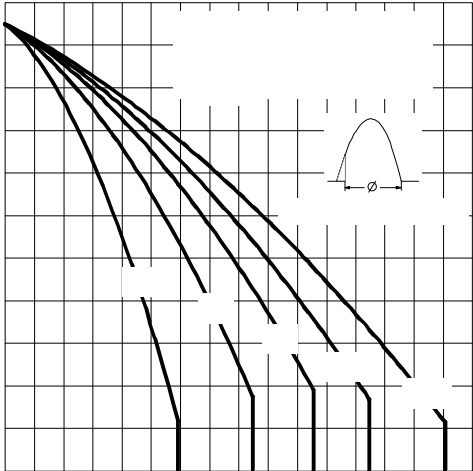


Fig. 3 - Current Ratings Characteristics

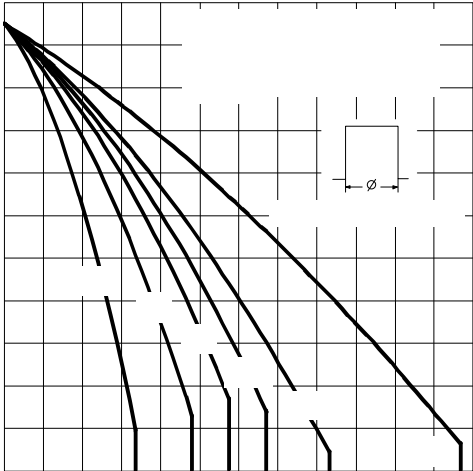


Fig. 4 - Current Ratings Characteristics

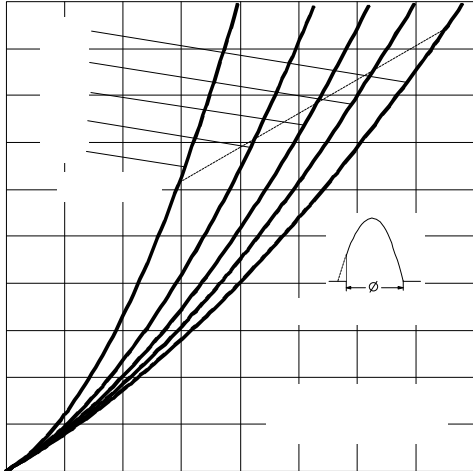


Fig. 5 - On-state Power Loss Characteristics

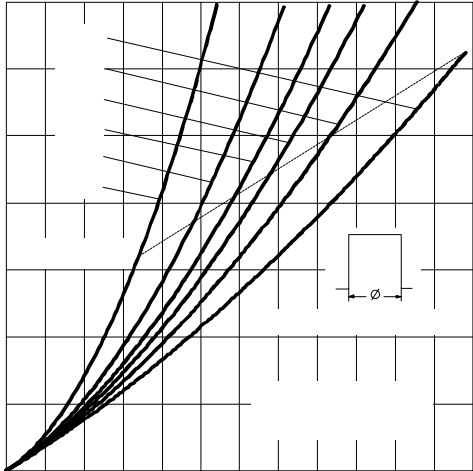
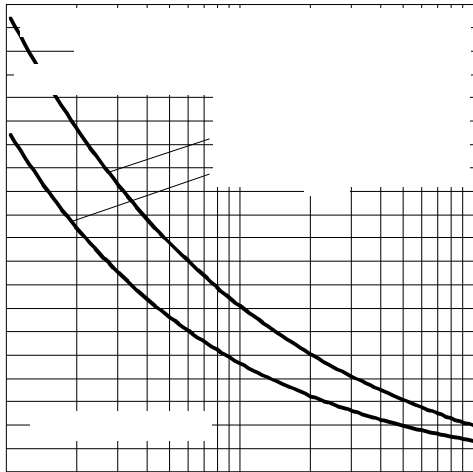
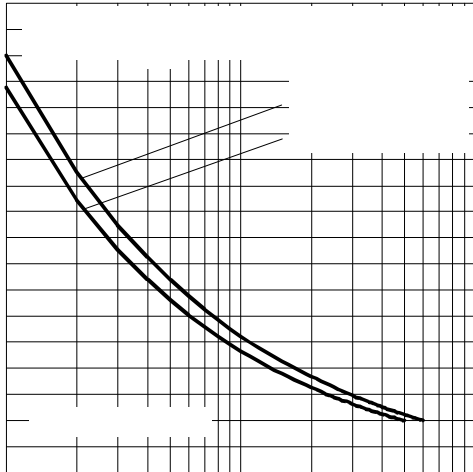


Fig. 6 - On-state Power Loss Characteristics



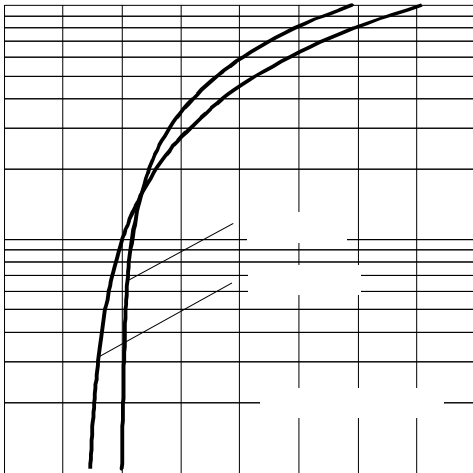


Fig. 9 - On-state Voltage Drop Characteristics

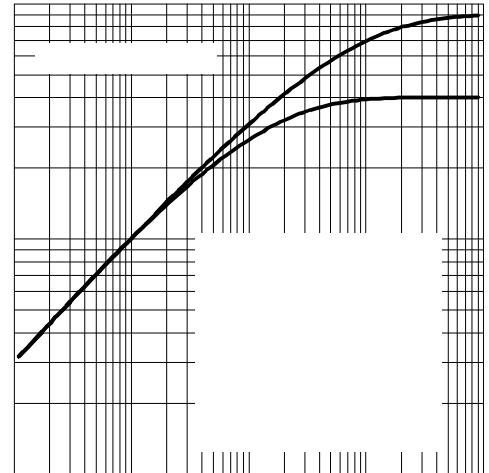


Fig. 10 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics

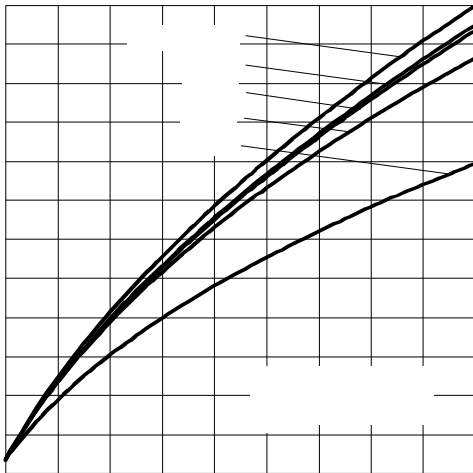


Fig. 11 - Reverse Recovered Charge Characteristics

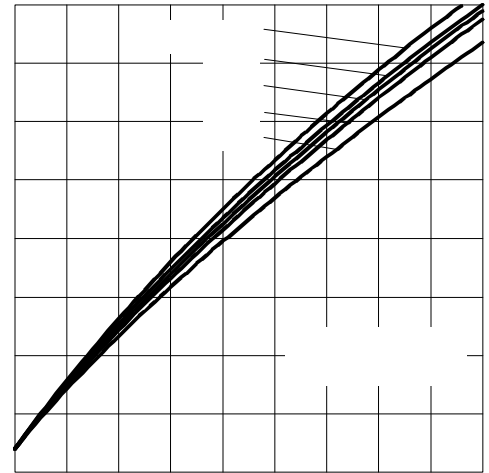
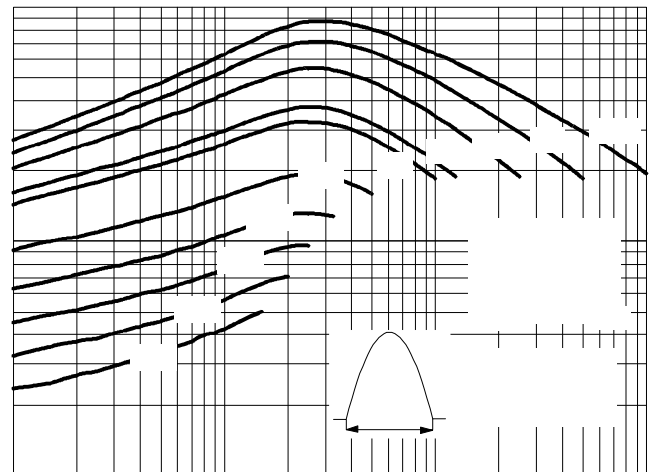
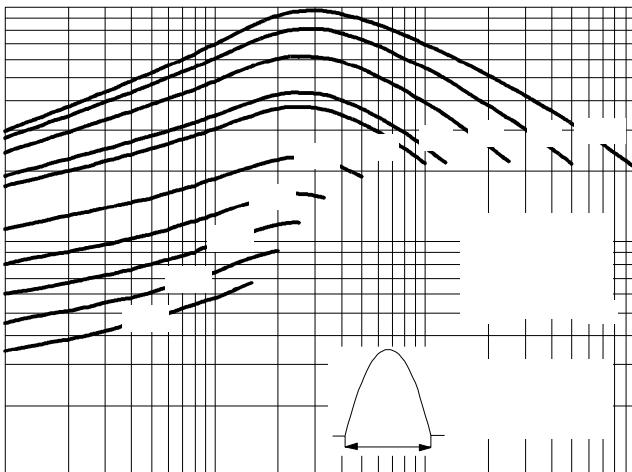


Fig. 12 - Reverse Recovery Current Characteristics



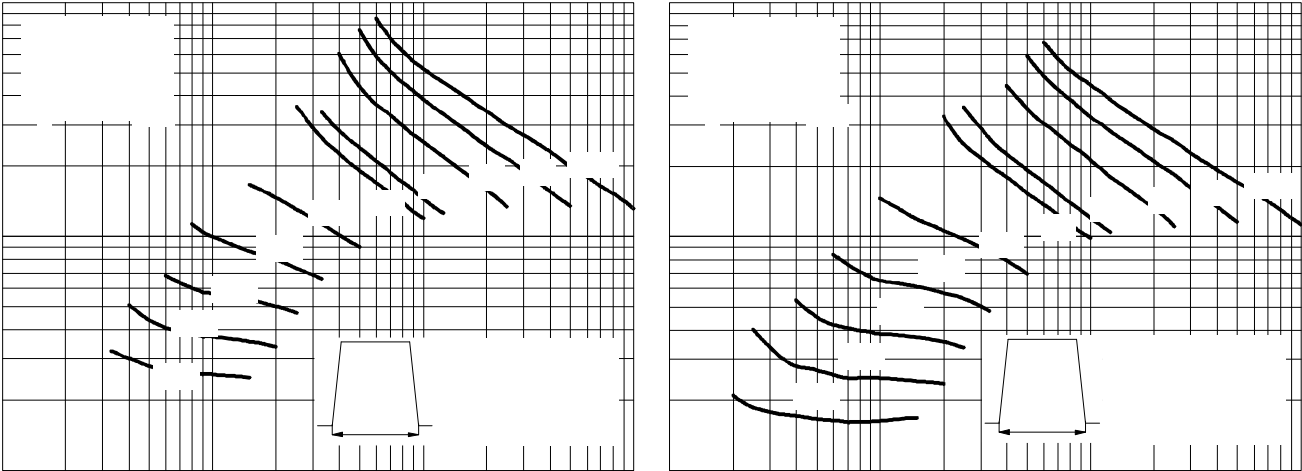


Fig. 14 - Frequency Characteristics

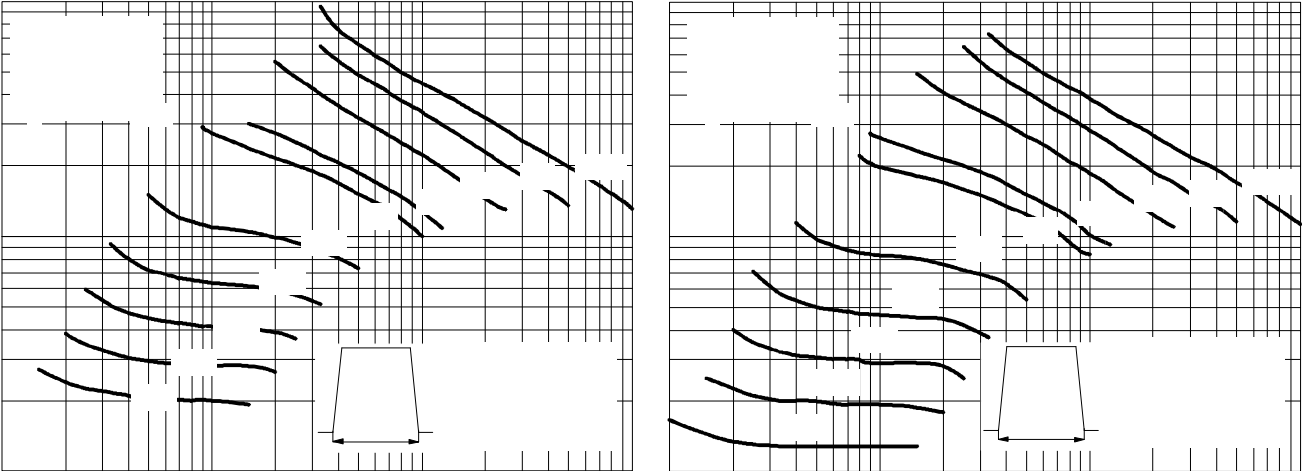
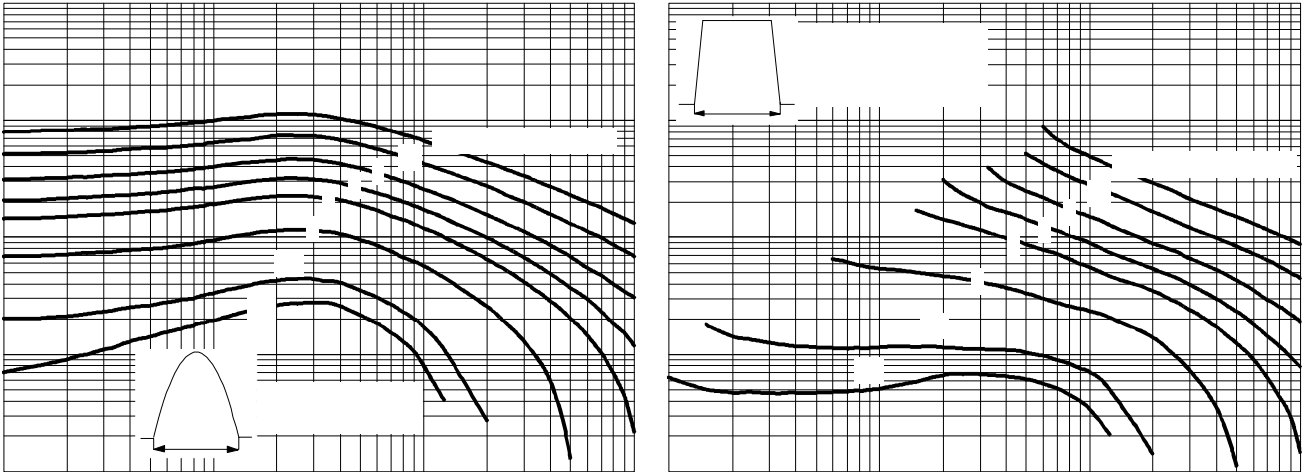


Fig. 15 - Frequency Characteristics



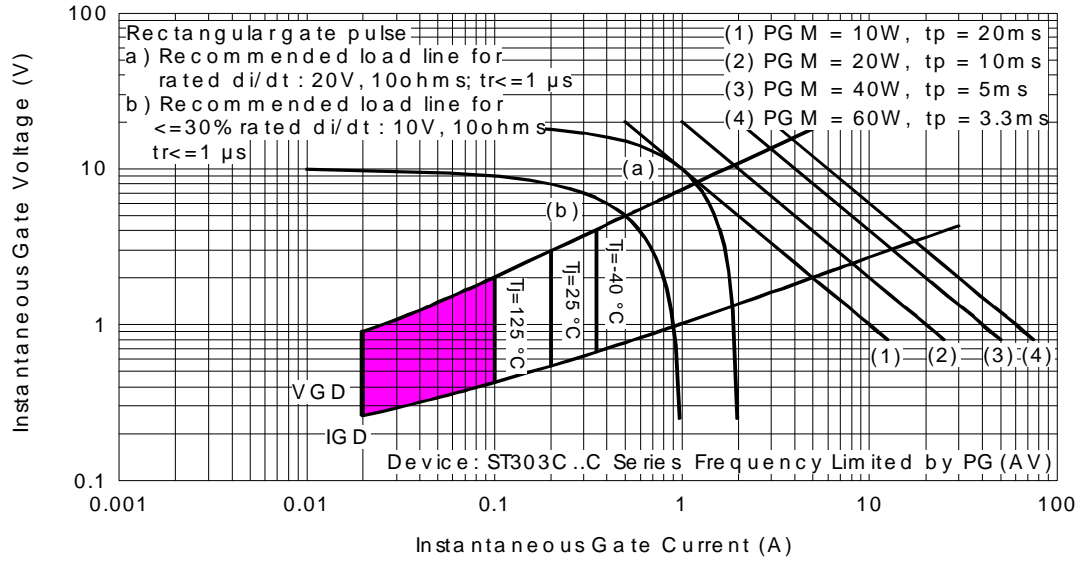


Fig. 17 - Gate Characteristics

## On-state Conduction

Parameter	ST303C..C	Units	Conditions
$V_{TM}$ Max. peak on-state voltage	2.16	V	$I_{TM} = 1255A, T_J = T_J \text{ max}, t_p = 10\text{ms sine wave pulse}$
$V_{T(TO)1}$ Low level value of threshold voltage	1.44		$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
$V_{T(TO)2}$ High level value of threshold voltage	1.48		$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
$r_{t1}$ Low level value of forward slope resistance	0.57	m $\Omega$	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
$r_{t2}$ High level value of forward slope resistance	0.56		$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
$I_H$ Maximum holding current	600	mA	$T_J = 25^\circ\text{C}, I_T > 30A$
$I_L$ Typical latching current	1000		$T_J = 25^\circ\text{C}, V_A = 12V, R_a = 6\Omega, I_G = 1A$

## Switching

Parameter	ST303C..C	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/ $\mu\text{s}$	$T_J = T_J \text{ max}, V_{DRM} = \text{rated } V_{DRM}$ $I_{TM} = 2 \times di/dt$
$t_d$ Typical delay time	0.83	$\mu\text{s}$	$T_J = 25^\circ\text{C}, V_{DM} = \text{rated } V_{DRM}, I_{TM} = 50A \text{ DC}, t_p = 1\mu\text{s}$ Resistive load, Gate pulse: 10V, 5 $\Omega$ source
$t_q$ Max. turn-off time (*)	Min 10 Max 30		$T_J = T_J \text{ max}, I_{TM} = 550A, \text{commutating } di/dt = 40A/\mu\text{s}$ $V_R = 50V, t_p = 500\mu\text{s}, dv/dt: \text{ see table in device code}$

(\*)  $t_q = 10$  to  $20\mu\text{s}$  for 400 to 800V devices;  $t_q = 15$  to  $30\mu\text{s}$  for 1000 to 1200V devices.

## Blocking

Parameter	ST303C..C	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ $\mu\text{s}$	$T_J = T_J \text{ max. linear to } 80\% V_{DRM}, \text{ higher value available on request}$
$I_{RRM}$ $I_{DRM}$ Max. peak reverse and off-state leakage current	50	mA	$T_J = T_J \text{ max}, \text{rated } V_{DRM}/V_{RRM} \text{ applied}$

## Triggering

Parameter	ST303C..C	Units	Conditions
$P_{GM}$ Maximum peak gate power	60	W	$T_J = T_J \text{ max}, f = 50\text{Hz}, d\% = 50$
$P_{G(AV)}$ Maximum average gate power	10		
$I_{GM}$ Max. peak positive gate current	10	A	$T_J = T_J \text{ max}, t_p \leq 5\text{ms}$
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J \text{ max}, t_p \leq 5\text{ms}$
$-V_{GM}$ Maximum peak negative gate voltage	5		
$I_{GT}$ Max. DC gate current required to trigger	200	mA	$T_J = 25^\circ\text{C}, V_A = 12V, R_a = 6\Omega$
$V_{GT}$ Max. DC gate voltage required to trigger	3	V	
$I_{GD}$ Max. DC gate current not to trigger	20	mA	$T_J = T_J \text{ max}, \text{rated } V_{DRM} \text{ applied}$

# ST303C..C Series

## Thermal and Mechanical Specification

Parameter	ST303C..C	Units	Conditions
T <sub>J</sub> Max. operating temperature range	-40 to 125	°C	
T <sub>stg</sub> Max. storage temperature range	-40 to 150		
R <sub>thJ-hs</sub> Max. thermal resistance, junction to heatsink	0.09 0.04	K/W	DC operation single side cooled DC operation double side cooled
R <sub>thC-hs</sub> Max. thermal resistance, case to heatsink	0.020 0.010	K/W	DC operation single side cooled DC operation double side cooled
F Mounting force, ± 10%	9800 (1000)	N (Kg)	
wt Approximate weight	83	g	
Case style	TO - 200AB (E-PUK)		See Outline Table

### ΔR<sub>thJ-hs</sub> Conduction

(The following table shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.010	0.010	0.007	0.007	K/W	T <sub>J</sub> = T <sub>J</sub> max.
120°	0.012	0.012	0.012	0.013		
90°	0.015	0.015	0.016	0.017		
60°	0.022	0.022	0.023	0.023		
30°	0.036	0.036	0.036	0.037		

## Ordering Information Table

**Device Code**

ST

30

3

C

12

C

H

K

1

①

②

③

④

⑤

⑥

⑦

⑧

⑨

⑩

- 1** - Thyristor
- 2** - Essential part number
- 3** - 3 = Fast turn off
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 = V<sub>RRM</sub> (See Voltage Rating Table)
- 6** - C = Puk Case TO-200AB (E-PUK)
- 7** - Reapplied dv/dt code (for t<sub>q</sub> test condition)
- 8** - t<sub>q</sub> code
- 9** - 0 = Eyelet term. (Gate and Aux. Cathode Unsoldered Leads)  
1 = Fast-on term. (Gate and Aux. Cathode Unsoldered Leads)  
2 = Eyelet term. (Gate and Aux. Cathode Soldered Leads)  
3 = Fast-on term. (Gate and Aux. Cathode Soldered Leads)
- 10** - Critical dv/dt:  
None = 500V/μsec (Standard value)

**dv/dt - t<sub>q</sub> combinations available**

	dv/dt (V/μs)	20	50	100	200	400
t <sub>q</sub> (μs) up to 800V	10	CN	DN	EN	<b>FN</b> *	HN
	12	CM	DM	EM	<b>FM</b> *	HM
	15	CL	DL	EL	<b>FL</b> *	HL
	20	CK	DK	EK	<b>FK</b> *	HK
t <sub>q</sub> (μs) only for 1000/1200V	15	CL	--	--	--	--
	18	CP	DP	--	--	--
	20	CK	DK	EK	<b>FK</b> *	HK
	25	CJ	DJ	EJ	<b>FJ</b> *	HJ
	30	--	DH	EH	FH	HH

\*Standard part number.

Outline Table

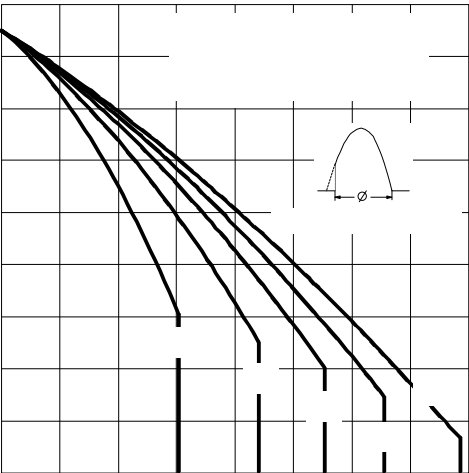
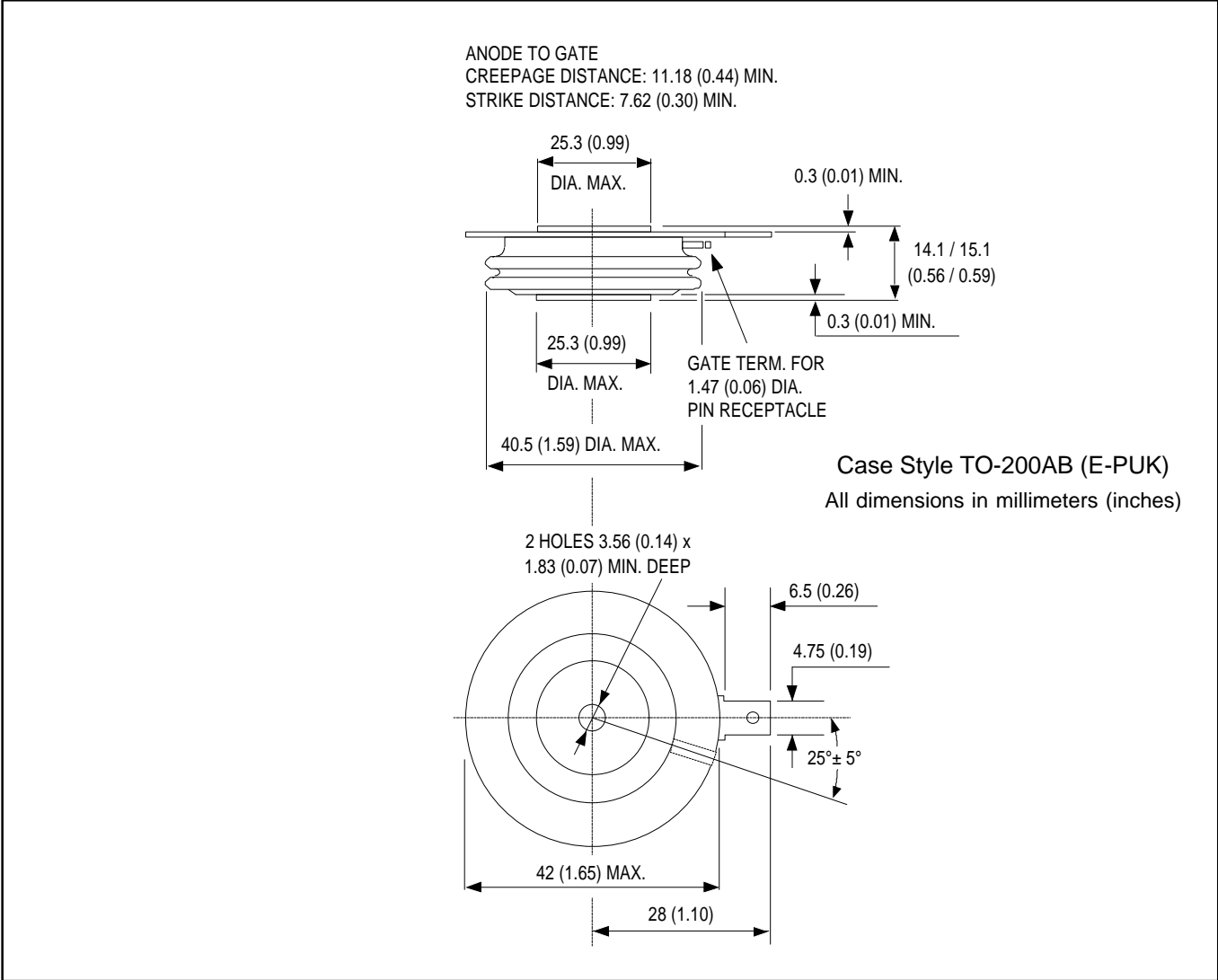


Fig. 1 - Current Ratings Characteristics

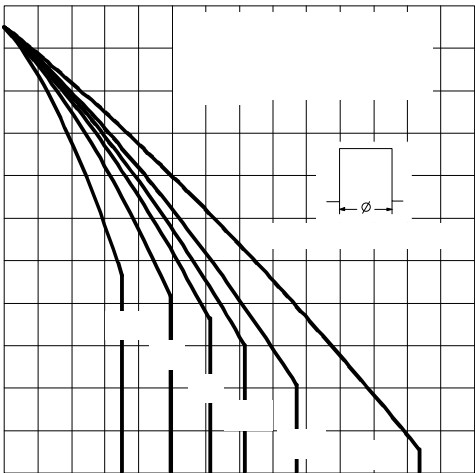


Fig. 2 - Current Ratings Characteristics